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Team Nexperia
1. Product profile

1.1 General description
Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a leadless ultra small SOD1608 (DFN1608D-2) Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

1.2 Features and benefits
- Average forward current: $I_{F(AV)} \leq 0.5$ A
- Reverse voltage: $V_R \leq 20$ V
- Low forward voltage $V_F \leq 410$ mV
- Low reverse current
- AEC-Q101 qualified
- Solderable side pads
- Package height typ. 0.37 mm
- Ultra small and leadless SMD plastic package

1.3 Applications
- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- LED backlight for mobile application
- Low power consumption applications
- Ultra high-speed switching
- Reverse polarity protection

1.4 Quick reference data

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$I_{F(AV)}$</td>
<td>average forward current</td>
<td>square wave; $\delta = 0.5; f = 20$ kHz; $T_{amb} \leq 130$ °C</td>
<td>[1]</td>
<td>-</td>
<td>0.5</td>
<td>A</td>
</tr>
<tr>
<td></td>
<td></td>
<td>square wave; $\delta = 0.5; f = 20$ kHz; $T_{sp} \leq 140$ °C</td>
<td>-</td>
<td>-</td>
<td>0.5</td>
<td>A</td>
</tr>
<tr>
<td>$V_R$</td>
<td>reverse voltage</td>
<td>$T_J = 25$ °C</td>
<td>-</td>
<td>-</td>
<td>20</td>
<td>V</td>
</tr>
<tr>
<td>$V_F$</td>
<td>forward voltage</td>
<td>$I_F = 500$ mA; pulsed; $t_p \leq 300$ $\mu$s; $\delta \leq 0.02; T_J = 25$ °C</td>
<td>-</td>
<td>360</td>
<td>410</td>
<td>mV</td>
</tr>
<tr>
<td>$I_R$</td>
<td>reverse current</td>
<td>$V_R = 10$ V; $T_J = 25$ °C</td>
<td>-</td>
<td>30</td>
<td>130</td>
<td>$\mu$A</td>
</tr>
<tr>
<td>$t_{tr}$</td>
<td>reverse recovery time</td>
<td>$I_R = 0.5$ A; $I_F = 0.5$ A; $I_{R(meas)} = 0.1$ A; $T_J = 25$ °C</td>
<td>-</td>
<td>3</td>
<td>-</td>
<td>ns</td>
</tr>
</tbody>
</table>

2. Pinning information

Table 2. Pinning information

<table>
<thead>
<tr>
<th>Pin</th>
<th>Symbol</th>
<th>Description</th>
<th>Simplified outline</th>
<th>Graphic symbol</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>K</td>
<td>cathode[1]</td>
<td><img src="image" alt="Simplified outline" /></td>
<td><img src="image" alt="Graphic symbol" /></td>
</tr>
<tr>
<td>2</td>
<td>A</td>
<td>anode</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

<table>
<thead>
<tr>
<th>Type number</th>
<th>Package</th>
<th>Name</th>
<th>Description</th>
<th>Version</th>
</tr>
</thead>
<tbody>
<tr>
<td>PMEG2005EPK</td>
<td>DFN1608D-2</td>
<td>Leadless ultra small plastic package; 2 terminals</td>
<td>SOD1608</td>
<td></td>
</tr>
</tbody>
</table>

4. Marking

Table 4. Marking codes

<table>
<thead>
<tr>
<th>Type number</th>
<th>Marking code</th>
</tr>
</thead>
<tbody>
<tr>
<td>PMEG2005EPK</td>
<td>1000 0000</td>
</tr>
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</table>

Fig 1. SOD1608 binary marking code description
5. Limiting values

Table 5. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_R$</td>
<td>reverse voltage</td>
<td>$T_j = 25 , ^\circ C$</td>
<td></td>
<td>20</td>
<td>V</td>
</tr>
<tr>
<td>$I_F$</td>
<td>forward current</td>
<td>$T_{sp} \leq 135 , ^\circ C$</td>
<td></td>
<td>0.7</td>
<td>A</td>
</tr>
<tr>
<td>$I_{F(AV)}$</td>
<td>average forward current</td>
<td>$\delta = 0.5; f = 20 , kHz; T_{amb} \leq 130 , ^\circ C$</td>
<td>[1]</td>
<td>0.5</td>
<td>A</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$\delta = 0.5; f = 20 , kHz; T_{sp} \leq 140 , ^\circ C$</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$I_{FRM}$</td>
<td>repetitive peak forward current</td>
<td>$t_p \leq 1 , ms; \delta \leq 0.5$</td>
<td></td>
<td>2</td>
<td>A</td>
</tr>
<tr>
<td>$I_{FSM}$</td>
<td>non-repetitive peak forward current</td>
<td>$\delta = 0.5; f = 20 , kHz; T_{j(init)} = 25 , ^\circ C$</td>
<td></td>
<td>3</td>
<td>A</td>
</tr>
<tr>
<td>$P_{tot}$</td>
<td>total power dissipation</td>
<td>$T_{amb} \leq 25 , ^\circ C$</td>
<td>[2]</td>
<td>390</td>
<td>mW</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$T_{amb} \leq 25 , ^\circ C$</td>
<td>[3]</td>
<td>830</td>
<td>mW</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$T_{amb} \leq 25 , ^\circ C$</td>
<td>[1]</td>
<td>1470</td>
<td>mW</td>
</tr>
<tr>
<td>$T_j$</td>
<td>junction temperature</td>
<td>-</td>
<td>-</td>
<td>150</td>
<td>°C</td>
</tr>
<tr>
<td>$T_{amb}$</td>
<td>ambient temperature</td>
<td>-</td>
<td>-55</td>
<td>150</td>
<td>°C</td>
</tr>
<tr>
<td>$T_{stg}$</td>
<td>storage temperature</td>
<td>-</td>
<td>-65</td>
<td>150</td>
<td>°C</td>
</tr>
</tbody>
</table>


6. Thermal characteristics

Table 6. Thermal characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_{th(j-a)}$</td>
<td>thermal resistance from junction to ambient</td>
<td>in free air</td>
<td>[1][2]</td>
<td>-</td>
<td>-</td>
<td>320  K/W</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>[1][3]</td>
<td>-</td>
<td>-</td>
<td>150  K/W</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>[1][4]</td>
<td>-</td>
<td>-</td>
<td>85   K/W</td>
</tr>
<tr>
<td>$R_{th(j-sp)}$</td>
<td>thermal resistance from junction to solder point</td>
<td></td>
<td>[5]</td>
<td>-</td>
<td>-</td>
<td>20   K/W</td>
</tr>
</tbody>
</table>

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses $P_R$ are a significant part of the total power losses.
FR4 PCB, standard footprint

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

FR4 PCB, mounting pad for cathode 1 cm²

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values
7. Characteristics

Table 7. Characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_F$</td>
<td>forward voltage</td>
<td>$I_F = 100 , mA$; pulsed; $t_p \leq 300 , \mu s$; $\delta \leq 0.02$; $T_j = 25^\circ C$</td>
<td>270</td>
<td>300</td>
<td>-</td>
<td>mV</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_F = 500 , mA$; pulsed; $t_p \leq 300 , \mu s$; $\delta \leq 0.02$; $T_j = 25^\circ C$</td>
<td>360</td>
<td>410</td>
<td>-</td>
<td>mV</td>
</tr>
<tr>
<td>$I_R$</td>
<td>reverse current</td>
<td>$V_R = 10 , V$; $T_j = 25^\circ C$</td>
<td>30</td>
<td>130</td>
<td>-</td>
<td>\mu A</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_R = 20 , V$; $T_j = 25^\circ C$</td>
<td>70</td>
<td>300</td>
<td>-</td>
<td>\mu A</td>
</tr>
<tr>
<td>$C_d$</td>
<td>diode capacitance</td>
<td>$V_R = 1 , V$; $f = 1 , MHz$; $T_j = 25^\circ C$</td>
<td>35</td>
<td>-</td>
<td>13</td>
<td>pF</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_R = 10 , V$; $f = 1 , MHz$; $T_j = 25^\circ C$</td>
<td>-</td>
<td>-</td>
<td>-</td>
<td>pF</td>
</tr>
<tr>
<td>$t_{rr}$</td>
<td>reverse recovery time</td>
<td>$I_F = 0.5 , A$; $I_R = 0.5 , A$; $I_{R(meas)} = 0.1 , A$; $T_j = 25^\circ C$</td>
<td>3</td>
<td>-</td>
<td>-</td>
<td>ns</td>
</tr>
<tr>
<td>$V_{FRM}$</td>
<td>peak forward recovery voltage</td>
<td>$I_F = 0.5 , A$; $dI_F/dt = 20 , mA/\mu s$; $T_j = 25^\circ C$</td>
<td>380</td>
<td>-</td>
<td>-</td>
<td>mV</td>
</tr>
</tbody>
</table>

Ceramic PCB, Al₂O₃, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values
Fig 5. Forward current as a function of forward voltage; typical values

Fig 6. Reverse current as a function of reverse voltage; typical values

Fig 7. Diode capacitance as a function of reverse voltage; typical values

Fig 8. Average forward power dissipation as a function of average forward current; typical values
**20 V, 0.5 A low VF MEGA Schottky barrier rectifier**

**Fig 9.** Average reverse power dissipation as a function of reverse voltage; typical values

- $T_j = 125 \, ^\circ C$
  - (1) $\delta = 1$
  - (2) $\delta = 0.9$
  - (3) $\delta = 0.8$
  - (4) $\delta = 0.5$

**Fig 10.** Average forward current as a function of ambient temperature; typical values

- FR4 PCB, standard footprint
  - $T_j = 150 \, ^\circ C$
  - (1) $\delta = 1$ (DC)
  - (2) $\delta = 0.5; f = 20 \, kHz$
  - (3) $\delta = 0.2; f = 20 \, kHz$
  - (4) $\delta = 0.1; f = 20 \, kHz$

- Ceramic PCB, Al$_2$O$_3$, standard footprint
  - $T_j = 150 \, ^\circ C$
  - (1) $\delta = 1$ (DC)
  - (2) $\delta = 0.5; f = 20 \, kHz$
  - (3) $\delta = 0.2; f = 20 \, kHz$
  - (4) $\delta = 0.1; f = 20 \, kHz$

**Fig 11.** Average forward current as a function of ambient temperature; typical values

- FR4 PCB, mounting pad for cathode 1 cm$^2$
  - $T_j = 150 \, ^\circ C$
  - (1) $\delta = 1$ (DC)
  - (2) $\delta = 0.5; f = 20 \, kHz$
  - (3) $\delta = 0.2; f = 20 \, kHz$
  - (4) $\delta = 0.1; f = 20 \, kHz$
8. Test information

Fig 13. Average forward current as a function of solder point temperature; typical values

\[ T_j = 150 \, ^\circ C \]

(1) \( \delta = 1 \) (DC)

(2) \( \delta = 0.5; \ f = 20 \, kHz \)

(3) \( \delta = 0.2; \ f = 20 \, kHz \)

(4) \( \delta = 0.1; \ f = 20 \, kHz \)

Fig 14. Reverse recovery definition
The current ratings for the typical waveforms are calculated according to the equations:

\[ I_{F(AV)} = I_M \times \delta \] with \( I_M \) defined as peak current, \( I_{RMS} = I_{F(AV)} \) at DC, and \( I_{RMS} = I_M \times \sqrt{\delta} \) with \( I_{RMS} \) defined as RMS current.

**8.1 Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.
9. Package outline

Fig 17. Package outline SOD1608 (DFN1608D-2)

10. Soldering

Fig 18. Reflow soldering footprint for SOD1608 (DFN1608D-2)
11. Revision history

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<th>Data sheet status</th>
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<td>*5 &quot;Limiting values&quot;: I_F corrected</td>
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<td>*7 &quot;Characteristics&quot;: t_{rr} and V_{FRM} added</td>
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<td>*Fig 14, and 15: added</td>
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12. Legal information

12.1 Data sheet status

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<th>Product status</th>
<th>Definition</th>
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<td>Objective [short] data sheet</td>
<td>Development</td>
<td>This document contains data from the objective specification for product development.</td>
</tr>
<tr>
<td>Preliminary [short] data sheet</td>
<td>Qualification</td>
<td>This document contains data from the preliminary specification.</td>
</tr>
<tr>
<td>Product [short] data sheet</td>
<td>Production</td>
<td>This document contains the product specification.</td>
</tr>
</tbody>
</table>

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20 V, 0.5 A low VF MEGA Schottky barrier rectifier

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